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# 2SC3793

Silicon NPN Epitaxial

# HITACHI

ADE-208-1091A (Z)  
2nd. Edition  
Mar. 2001

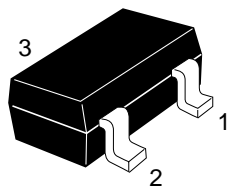
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## Application

UHF local oscillator

## Outline

MPAK



- 1. Emitter
- 2. Base
- 3. Collector

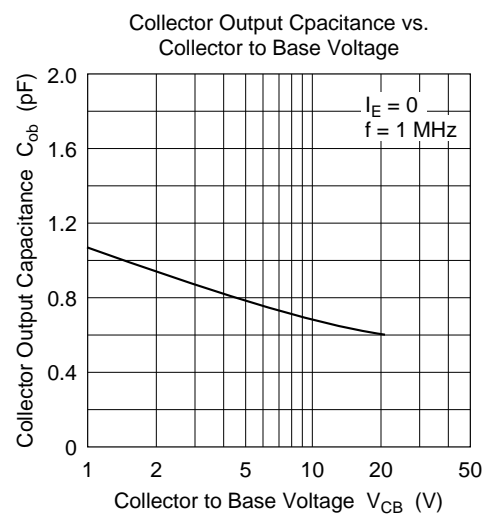
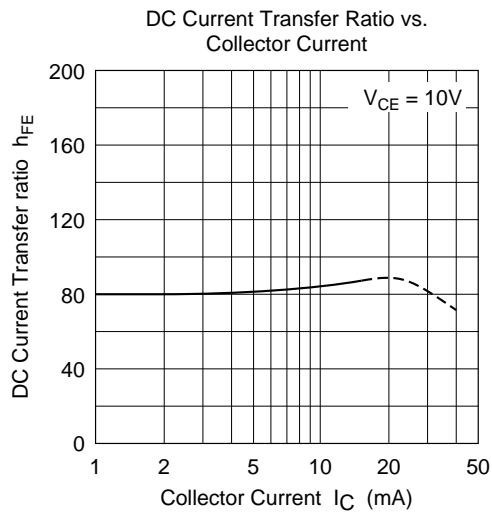
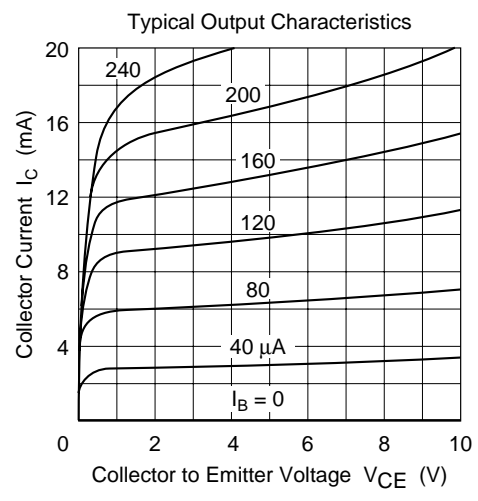
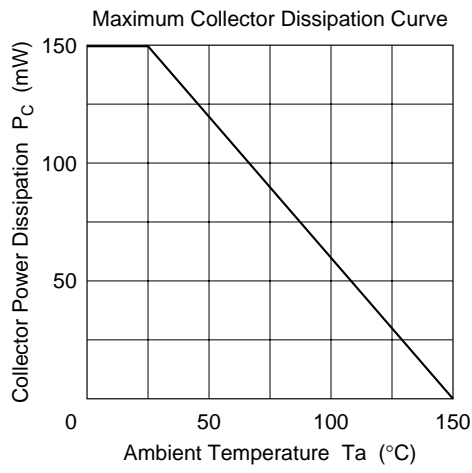
Note: Marking is "IP-".

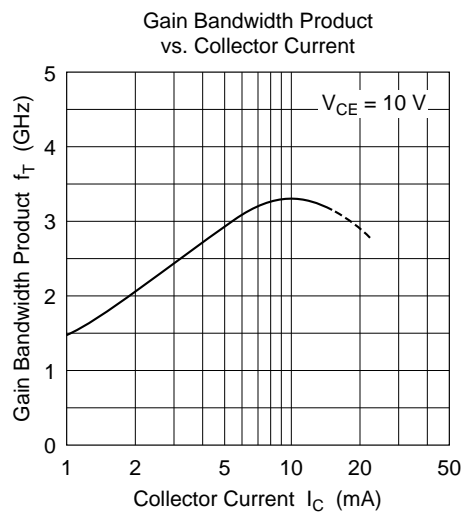
**Absolute Maximum Ratings** ( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{\text{CBO}}$	20	V
Collector to emitter voltage	$V_{\text{CEO}}$	15	V
Emitter to base voltage	$V_{\text{EBO}}$	3	V
Collector current	$I_{\text{C}}$	50	mA
Collector power dissipation	$P_{\text{C}}$	150	mW
Junction temperature	$T_{\text{j}}$	150	$^\circ\text{C}$
Storage temperature	$T_{\text{stg}}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** ( $T_a = 25^\circ\text{C}$ )

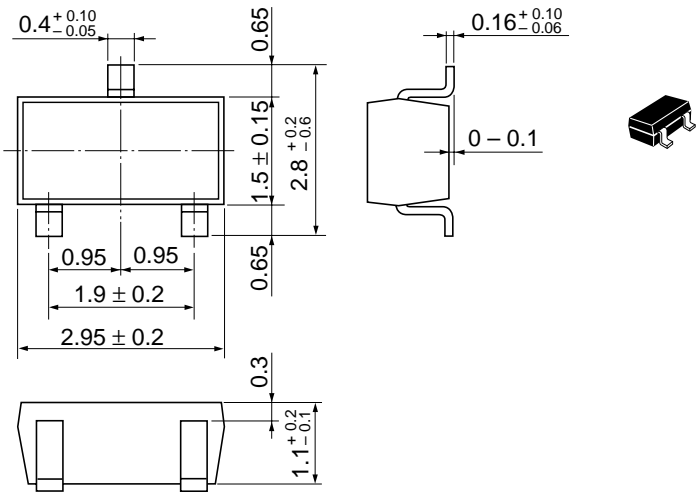
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	20	—	—	V	$I_{\text{C}} = 10\text{ }\mu\text{A}$ , $I_{\text{E}} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	15	—	—	V	$I_{\text{C}} = 1\text{ mA}$ , $R_{\text{BE}} = \infty$
Collector cutoff current	$I_{\text{CBO}}$	—	—	1	$\mu\text{A}$	$V_{\text{CB}} = 15\text{ V}$ , $I_{\text{E}} = 0$
Emitter cutoff current	$I_{\text{EBO}}$	—	—	1	$\mu\text{A}$	$V_{\text{EB}} = 3\text{ V}$ , $I_{\text{C}} = 0$
DC current transfer ratio	$h_{\text{FE}}$	30	—	200		$V_{\text{CE}} = 10\text{ V}$ , $I_{\text{C}} = 5\text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	—	0.5	V	$I_{\text{C}} = 20\text{ mA}$ , $I_{\text{B}} = 4\text{ mA}$
Collector output capacitance	$C_{\text{ob}}$	—	0.7	1	pF	$V_{\text{CB}} = 10\text{ V}$ , $I_{\text{E}} = 0$ , $f = 1\text{ MHz}$
Gain bandwidth product	$f_{\text{T}}$	—	2.9	—	GHz	$V_{\text{CE}} = 10\text{ V}$ , $I_{\text{C}} = 5\text{ mA}$





Package Dimensions

As of January, 2001  
Unit: mm



Hitachi Code	MPAK
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.011 g

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